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## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Inge Application of:

Examiner: S. Hu

TOHRU DEN, ET AL.

Group Art Unit: 2811

Application No.: 09/666,605

Filed: September 20, 2000

For: STRUCTURE HAVING

PORES, DEVICE USING THE SAME, AND

MANUFACTURING METHODS

THEREFOR ) December 31, 2002

Commissioner for Patents Washington, D.C. 20231

## SUPPLEMENT TO AMENDMENT

Sir:

Further to the Amendment dated December 13, 2002, Applicants are enclosing herewith an English-language translation of Japan 11-200090 (Japan '090) for the Examiner's convenience.

As discussed in the Amendment, Japan '090 is not seen to disclose at least the feature of pores disposed above a surface of the substrate where no electroconductive layer is formed. As shown in Figures 6(a), 7(a) and 7(b) of Japan '090, all of nanoholes (14) are disposed entirely above conductive layer (11).

In view of the foregoing, and in view of the amendments and remarks set forth in the Amendment dated December 13, 2002, Applicants submit that the application is fully in condition for allowance, and such action is courteously solicited.

Applicants' undersigned attorney may be reached in our Costa Mesa,

California office at (714) 540-8700. All correspondence should continue to be directed to
our below-listed address.

Respectfully submitted,

Attorney for Applicants

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